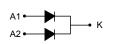
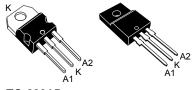
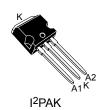


300 V ultrafast rectifier





TO-220AB TO-220FPAB



D²PAK

Product status STTH2003

Product summary				
I _{F(AV)}	2 x 10 A			
V _{RRM}	300 V			
T _j (max.)	175 °C			
V _F (typ.)	0.85 V			
t _{rr} (max.)	25 ns			

Features

- Combines highest recovery and reverse voltage performance
- · Ultra-fast, soft and noise-free recovery
- Insulated package: TO-220FPAB
 - Insulating voltage = 2000 V_{RMS} sine
- ECOPACK[®]2 compliant component for D²PAK on demand

Applications

- Secondary rectification
- · Switching diode
- · Telecom power supply
- DC/DC converter

Description

The STTH2003 is a dual center tap fast recovery epitaxial diodes suited for switch mode power supply and high frequency DC/DC converters.

Packaged in TO-220AB, TO-220FPAB, I²PAK or D²PAK, this device is especially intended for secondary rectification.



1 Characteristics

Table 1. Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified)

Symbol		Value	Unit			
V _{RRM}	Repetitive peak reverse voltage			300	V	
I _{F(RMS)}	Forward rms current				30	Α
	$I_{F(AV)}$ Average forward current δ = 0.5, square wave	TO-220AB, D2PAK, I2PAK	T _C = 140 °C	Per diode	10	
I _{F(AV)}		TO-220FPAB	T _C = 115 °C			Α
		All types	Per device		20	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			110	Α	
T _{stg}	Storage temperature range			-65 to +175	°C	
Tj	Maximum operating junction temperature			175	°C	

Table 2. Thermal resistance parameters

Symbol	Parameter			Value	Unit
		TO-220AB, D ² PAK, I ² PAK	Per diode	2.5	
D	R _{th(j-c)} Junction to case	TO-220FPAB	Per diode	4.6	°C/W
►th(j-c)		TO-220AB, D ² PAK, I ² PAK	Total	1.3	
		TO-220FPAB	Total	4.0	
D	Counling	TO-220AB, D ² PAK, I ² PAK	-220AB, D²PAK, I²PAK		°C/W
R _{th(c)} Coupling	Coupling	TO-220FPAB		3.5	C/VV

For more information, please refer to the following application note:

• AN5088: Rectifiers thermal management, handling and mounting recommendations

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j \text{ (diode1)}} = P_{\text{(diode1)}} x R_{\text{th(j-c)}} \text{ (per diode)} + P_{\text{(diode2)}} x R_{\text{th(c)}}$

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I_ (1)	I _R ⁽¹⁾ Reverse leakage current	T _j = 25 °C	V _R = 300 V	-		20	μА
IR ` '		T _j = 125 °C		-	30	300	
V _E (2)	V _F ⁽²⁾ Forward voltage drop		I _F = 10 A	-		1.25	V
VF (=) FOI	i orwaru voltage urop	T _j = 125 °C	IF - IO A	-	0.85	1.0	

- 1. Pulse test: $t_p = 5$ ms, $\delta < 2\%$
- 2. Pulse test: $t_p = 380 \,\mu\text{s}, \, \delta < 2\%$

To evaluate the conduction losses, use the following equation:

 $P = 0.75 \times I_{F(AV)} + 0.025 \times I_{F}^{2} (RMS)$

For more information, please refer to the following application notes related to the power losses:

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- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses in a power diode

Table 4. Recovery characteristics (per diode)

Symbol	Parameter		Test conditions			Max.	Unit
	Davis and a second time at 1 = 25 °C		I _F = 0.5 A, I _{rr} = 0.25 A, I _R = 1 A			25	no
t _{rr} Reverse recovery time	T _j = 25 °C	$I_F = 1 \text{ A}, V_R = 30 \text{ V}, dI_F/dt = -50 \text{ A/}\mu\text{s}$	-		35	– ns	
t _{fr}	Forward recovery time	T _j = 25 °C	$I_F = 10 \text{ A}, V_{FR} = 1.1 \text{ x } V_{Fmax}, dI_F/dt = 100 \text{ A/}\mu\text{s}$	-		230	ns
V _{FP}	Peak forward voltage	T _j = 25 °C	I _F = 10 A, dI _F /dt = 100 A/μs	-		3.5	V
I _{RM}	Reverse recovery current	T. = 125 °C	$I_F = 10 \text{ A}, V_{CC} = 200 \text{ V}, dI_F/dt = -200 \text{ A/}\mu\text{s}$	-		8	Α
S factor	Softness factor	1, - 125 0		-	0.3		-

1.1 Characteristics (curves)

Figure 1. Conduction losses versus average forward current (per diode)

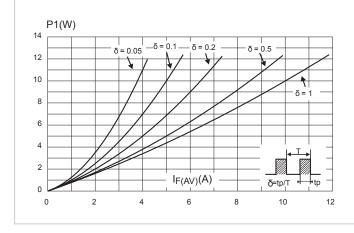


Figure 2. Forward voltage drop versus forward current (maximum values, per diode)

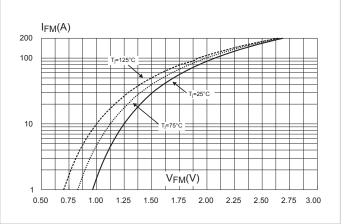


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration (TO-220AB, D²PAK, I²PAK)

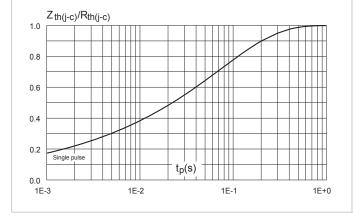
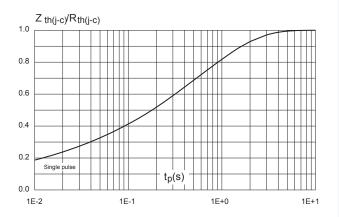


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration (TO-220FPAB)



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Figure 5. Peak reverse recovery current versus dl_F/dt (typical values, per diode)

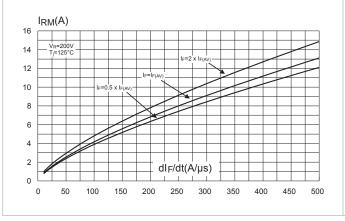


Figure 6. Reverse recovery time versus dl_F/dt (typical values, per diode)

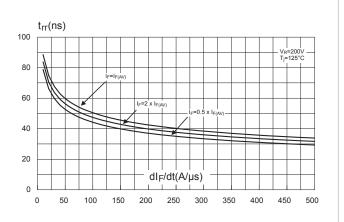


Figure 7. Softness factor versus dl_F/dt (typical values, per diode)

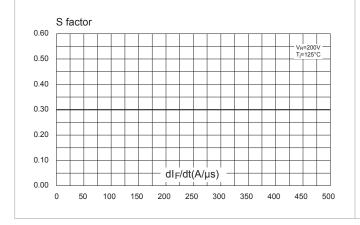


Figure 8. Relative variation of dynamic parameters versus junction temperature (reference: $T_i = 125$ °C)

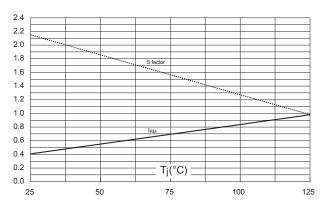


Figure 9. Transient peak forward voltage versus dl_F/dt (typical values, per diode) (TO-220AB)

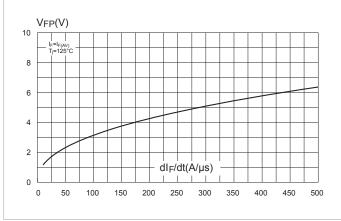
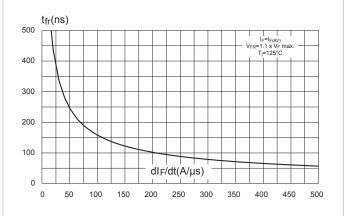


Figure 10. Forward recovery time versus dl_F/dt (typical values, per diode)



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Figure 11. Thermal resistance, junction to ambient, versus copper surface under tab (epoxy printed board FR4, e_{Cu} = 35µm) (D²PAK)

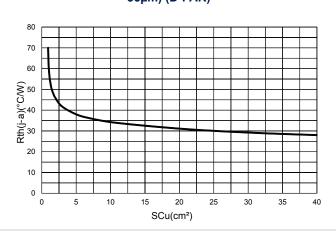
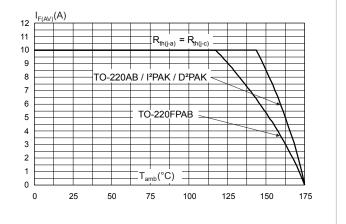


Figure 12. Average forward current versus ambient temperature (δ = 0.5, per diode)



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2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 D²PAK package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

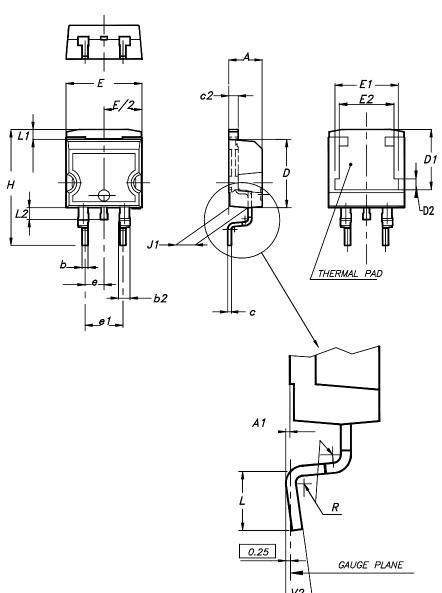


Figure 13. D²PAK package outline

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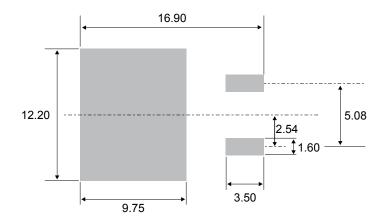
Note:

This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 5. D²PAK package mechanical data

	Dimensions				
Ref.	Millir	neters	Inches (for re	ference only)	
	Min.	Max.	Min.	Max.	
A	4.36	4.60	0.172	0.181	
A1	0.00	0.25	0.000	0.010	
b	0.70	0.93	0.028	0.037	
b2	1.14	1.70	0.045	0.067	
С	0.38	0.69	0.015	0.027	
c2	1.19	1.36	0.047	0.053	
D	8.60	9.35	0.339	0.368	
D1	6.90	8.00	0.272	0.311	
D2	1.10	1.50	0.043	0.060	
Е	10.00	10.55	0.394	0.415	
E1	8.10	8.90	0.319	0.346	
E2	6.85	7.25	0.266	0.282	
е	2.5	4 typ.	0.100		
e1	4.88	5.28	0.190	0.205	
Н	15.00	15.85	0.591	0.624	
J1	2.49	2.90	0.097	0.112	
L	1.90	2.79	0.075	0.110	
L1	1.27	1.65	0.049	0.065	
L2	1.30	1.78	0.050	0.070	
R	0.4	typ.	0.0)15	
V2	0°	8°	0°	8°	

Figure 14. D²PAK recommended footprint (dimensions in mm)



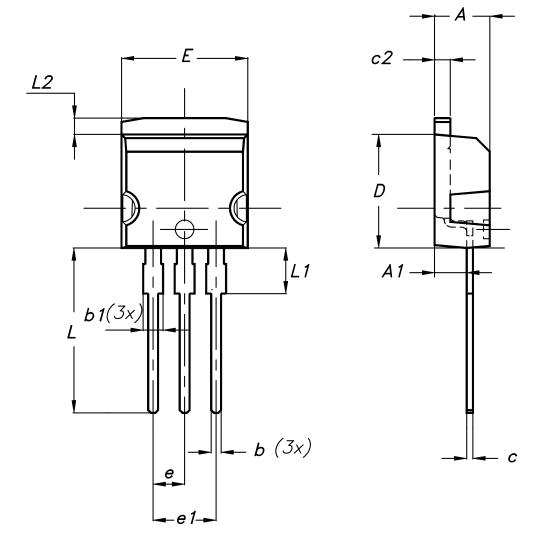
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2.2 I²PAK package information

- Epoxy meets UL 94,V0
- Cooling method: by conduction (C)

Figure 15. I²PAK package outline



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Table 6. I²PAK package mechanical data

	Dimensions				
Ref.	Millin	neters	Inches (for re	ference only)	
	Min.	Max.	Min.	Max.	
Α	4.40	4.60	0.173	0.181	
A1	2.40	2.72	0.094	0.107	
b	0.61	0.88	0.024	0.035	
b1	1.14	1.70	0.044	0.067	
С	0.49	0.70	0.019	0.028	
c2	1.23	1.32	0.048	0.052	
D	8.95	9.35	0.352	0.368	
е	2.40	2.70	0.094	0.106	
e1	4.95	5.15	0.195	0.203	
E	10.00	10.40	0.394	0.409	
L	13.00	14.00	0.512	0.551	
L1	3.50	3.93	0.138	0.155	
L2	1.27	1.40	0.050	0.055	



2.3 TO-220AB package information

Epoxy meets UL 94,V0

Cooling method: by conduction (C)
 Recommended torque value: 0.55 N·m

• Maximum torque value: 0.70 N·m

Figure 16. TO-220AB package outline

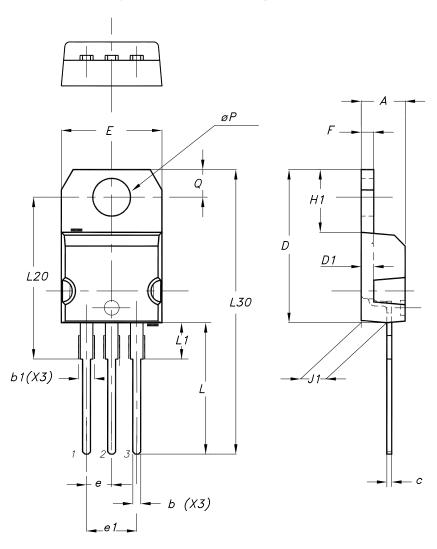


Table 7. TO-220AB package mechanical data

	Dimensions				
Ref.	Millimeters		Inches (for re	ference only)	
	Min.	Max.	Min.	Max.	
Α	4.40	4.60	0.173	0.181	
b	0.61	0.88	0.240	0.035	
b1	1.14	1.55	0.045	0.061	

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	Dimensions					
Ref.	Millir	neters	Inches (for re	ference only)		
	Min.	Max.	Min.	Max.		
С	0.48	0.70	0.019	0.028		
D	15.25	15.75	0.600	0.620		
D1	1.2	7 typ.	0.050	typ.		
E	10.00	10.40	0.394	0.409		
е	2.40	2.70	0.094	0.106		
e1	4.95	5.15	0.195	0.203		
F	1.23	1.32	0.048	0.052		
H1	6.20	6.60	0.244	0.260		
J1	2.40	2.72	0.094	0.107		
L	13.00	14.00	0.512	0.551		
L1	3.50	3.93	0.138	0.155		
L20	16.40 typ.		0.646 typ.			
L30	28.90 typ.		1.138	3 typ.		
θР	3.75	3.85	0.148	0.152		
Q	2.65	2.95	0.104	0.116		



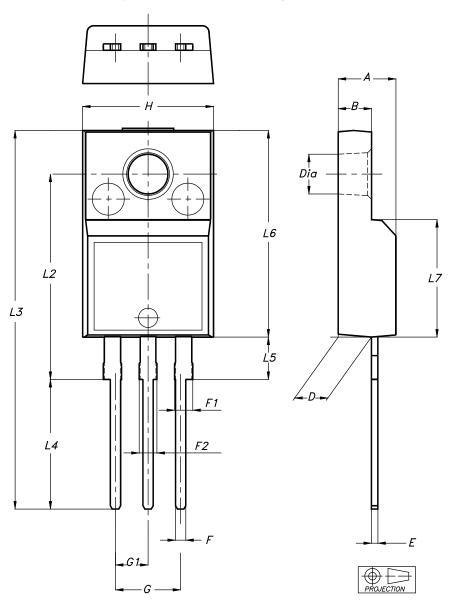
2.4 TO-220FPAB package information

• Epoxy meets UL 94,V0

Cooling method: by conduction (C)
 Recommended torque value: 0.55 N·m

Maximum torque value: 0.70 N⋅m

Figure 17. TO-220FPAB package outline



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Table 8. TO-220FPAB package mechanical data

	Dimensions				
Ref.	Millin	neters	Inches (for re	ference only)	
	Min.	Max.	Min.	Max.	
Α	4.40	4.60	0.1739	0.1818	
В	2.50	2.70	0.0988	0.1067	
D	2.50	2.75	0.0988	0.1087	
E	0.45	0.70	0.0178	0.0277	
F	0.75	1.00	0.0296	0.0395	
F1	1.15	1.70	0.0455	0.0672	
F2	1.15	1.70	0.0455	0.0672	
G	4.95	5.20	0.1957	0.2055	
G1	2.40	2.70	0.0949	0.1067	
Н	10.00	10.40	0.3953	0.4111	
L2	16.00	0 typ.	0.6324 typ.		
L3	28.60	30.60	1.1304	1.2095	
L4	9.80	10.60	0.3874	0.4190	
L5	2.90	3.60	0.1146	0.1423	
L6	15.90	16.40	0.6285	0.6482	
L7	9.00	9.30	0.3557	0.3676	
Dia	3.00	3.20	0.1186	0.1265	

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3 Ordering information

Table 9. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH2003CT	STTH2003CT	TO-220AB	1.95 g	50	Tube
STTH2003CG	STTH2003CG	D ² PAK	1.38 g	50	Tube
STTH2003CG-TR	STTH2003CG	D ² PAK	1.38 g	1000	Tape and reel
STTH2003CFP	STTH2003CFP	TO-220FPAB	1.90 g	50	Tube
STTH2003CR	STTH2003CR	I ² PAK	1.50 g	50	Tube

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Revision history

Table 10. Document revision history

Date	Revision	Changes
Aug-2003	7G	Previous release
26-Mar-2007	8	Removed ISOWATT package
11-Feb-2011	9	Updated base quantity for tape and reel delivery. Corrected temperature in <i>Table 1</i> . Added warning paragraph above <i>Table 7</i> .
06-Sep-2011	10	Updated Table 2. Added Figure 12.
28-May-2015	11	Updated features, <i>Table 1: "Device summary"</i> and packages silhouette in cover page. Updated <i>Section 1: "Characteristics"</i> . Updated <i>Section 2.2: "D²PAK package information"</i> .
07-Aug-2018	12	Updated I²PAK package information. Minor text changes to improve readability.



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